

June 2018







ST25DV-I2C Product 2

- ST25DV-I2C chip belongs to ST25 NFC / RFID Tags & Readers family
- ST25DV-I2C product is Dynamic Tag with following main features:
 - NFC Forum Tag Type 5 certified



- ISO15693 RF interface
- Two-wire, slave I²C up to 1MHz interface (I²C fast mode) 1.8V to 5.5V
- Up to 64kbit EEPROM memory
- Multiple 64-bit passwords for data protection
- 40 years data retention & 1Mcycles erase/write
- 7 Interrupts modes, configurable on dedicated GPO pin (MCU wake-up, ...)
- Energy harvesting through RF
- Fast Transfer Mode, thanks to 256 Bytes buffer
- Extended temperature range, industrial grade 8 -> NEW
- 8 pin or 10 or 12 pin package versions → **NEW**: WLCSP package added



25DV-I2C series is the natural evolution of M24LR series



Main ST25DV-I2C Market Segments 3

Smart Industry





Factory Automation, Industrial Lighting

Smart Home





Home Automation, Security Systems

Smart City





Metering, Street Lighting

Smart Things





Healthcare, Wellness

Smart banking card





CVV credit card, Badge





ST25DV-I2C Combined Use Cases

Device programming in production



Servicing & Maintenance





- Download records history contactless
- **Update** parameters even if device is powered off thanks to NFC phone
- Quick FW upgrade via Fast Transfer Mode

End user experience





- Access to Web page (URL) or get link for Android application (AAR)
- e-warranty card & customer registration

Commissioning for Wireless industrial network







Battery less applications





Product without battery thanks to **Energy Harvesting** feature





Typical NFC Type 5 Range

NFC phone



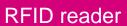
ISO15693 (26kb/s)



Up to 7cm (3in.)



ISO15693 (26kb/s)





Up to 1m (3ft)

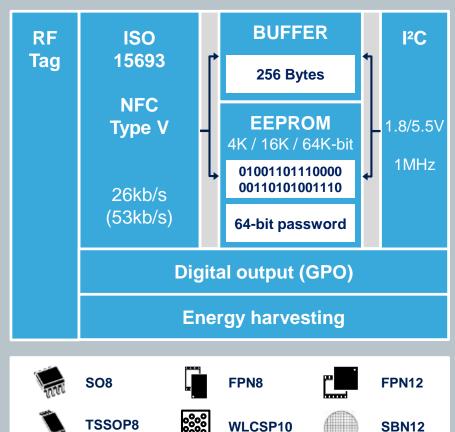




ST25DV-I2C Dynamic NFC Tag



ST25DV04K / 16K / 64K



Use cases

- Fast data exchange with NFC phones / HF readers. Long range
 - Fast data transfer for MCU FW upgrade, Fast data exchange
 - Parameters settings and update, with in the box programming
 - Datalog download
- Battery less applications

Key Features

- ISO15693 and NFC Type V
- Fast data transfer thanks to 256 Bytes buffer
- Low Power mode, < 1μA power consumption in Standby
- -40 to +125°C (I2C) industrial Grade 8 temperature range
- Energy harvesting function through RF

Key Benefits

- Smart applications using a flexible interrupt GPO
- Enhanced protection with multiple 64-bit passwords
- Same 28.5pF internal RF tuning capacitor, as in M24LR



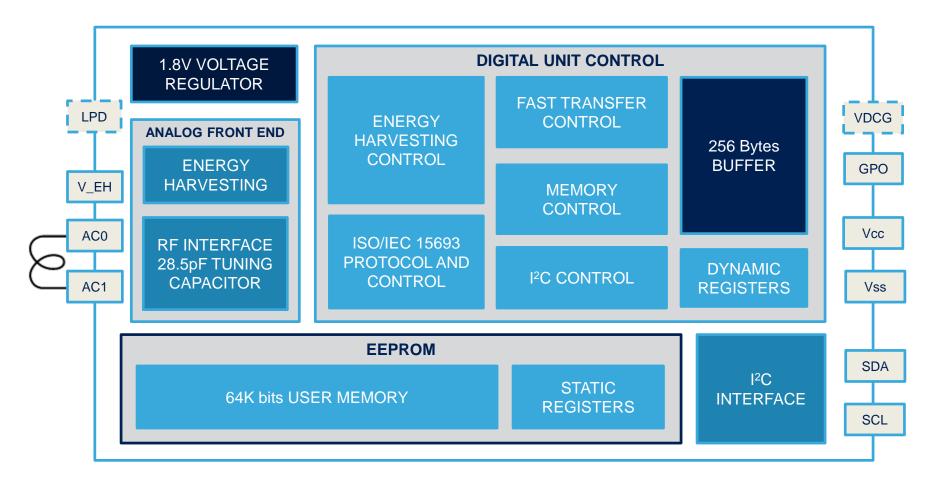


ST25DV-I2C Key Features _____

ST25DV-I2C series

Contactless Interface	ISO15693 / NFC Forum Type 5 + annexes 3 & 4
RF range	Long range, up to 100cm
RF speed	up to 53kbps (26kbps standard)
Single supply voltage	1.8V to 5.5V
Serial Interface	I2C @1MHz
Extra Features	GPO: 7 interrupts modes (Open Drain or CMOS) Energy Harvesting Low Power Mode
Memory format & size	EEPROM data - 4 / 16 / 64-kbit
Data retention	40-year at +55°C
Erase/Write cycles	1M cycles at +25°C / 600k cycles at + 85°C 500k cycles at +105°C / 400k cycles at +125°C
Fast Transfer Mode	256 Bytes memory Buffer
Data protection	Password 64-bit
Temperature range	Grade 6: -40°C to +85°C Grade 8: -40°C to +125°C (+105°C for RF)
Package	SO8 / TSSOP8 / FPN8 / FPN12 / WLCSP10 / SBN12

ST25DV-I2C Block Diagram 800



*LPD, VDGC pin are only available with FPN12 and WLCSP10 package version





ST25DV-I2C vs M24LR / M24SR (1/2)

	M24SR series	M24LR series	ST25DV-I2C series
Contactless Interface	ISO14443A NFC Type 4	ISO15693 NFC compatible	ISO15693 NFC Type 5
RF range	Short range (up to 10cm)	Long range (up to 100cm)	Long range (up to 100cm)
RF speed	106kbps	up to 53kbps (26kbps standard)	up to 53kbps (26kbps standard)
Serial Interface	I2C @1MHz	I2C @400kHz	I2C @1MHz
Fast Transfer mode	No	No	Yes, FIFO buffer (256-Byte)
Energy Harvesting	No	Yes	Yes
Digital output	Open-Drain GPO	Open-Drain GPO	OD or CMOS GPO
Extra features	RF Disable	-	Low Power mode





ST25DV-I2C vs M24LR / M24SR (2/2) 1010

	M24SR series	M24LR series	ST25DV-I2C series
Memory format	EEPROM (preformatted NDEF)	EEPROM data	EEPROM data
Memory size	2 / 4 / 16 / 64-Kbit	4 / 16 / 64-Kbit	4 / 16 / 64-Kbit
Data protection	Password 128-bit	Password 32-bit	Password 64-bit
Data retention	200 years at +55°C	40 years at +55°C	40 years at +55°C
Erase/Write cycles	1M cycles at +25°C 600k cycles at +85°C 500k cycles at +105°C	1M cycles at +25°C 100k cycles at +85°C	1M cycles at +25°C 600k cycles at +85°C 500k cycles at +105°C 400k cycles at +125°C
Temperature range	-40°C to +85°C -40°C to +105°C (85°C RF)	-40°C to +85°C	-40°C to +85°C -40°C to +125°C (105°C RF)
Package	SO8 / TSSOP8 / FPN8 / SBN12	SO8 / TSSOP8 / FPN8 / SBN12 *	SO8 / TSSOP8 / FPN8 / FPN12 / WLCSP10 / SBN12 *







Design Compatibility

M24SR

ISO14443 RF interface

- NFC compliant (type 4)
- Short Range (up to 10cm)
- High speed 106kb/s
- Passive RF
- 25pF internal tuning cap

High speed I2C

- 1MHz
- 2.7-5.5V
- NDEF data format

Enhanced EEPROM

- 200 years data retention
- 1 Million erase-write cycles
- 128-bit password protection

Compatible antenna design

Same packages and pinout (8-pin version)

4K, 16K and 64Kbit versions

ST25DV-I2C M24LR

ISO15693 RF interface

- NFC compliant (type 5)
- Long Range (up to 1m with RFID readers)
- 26kb/s data rate
- Passive RF
- 27.5pF / 28.5pF equivalent internal tuning cap
- Energy Harvesting

Low voltage I2C

- 400kHz / 1MHz
- 1.8-5.5V
- EEPROM data format
- NDEF by user

Standard EEPROM

- 40 years data retention
- 1 Million erase-write cycles
- 64-bit (32-bit) password protection





Data Protection 12

- User and System memory data protection thanks to a password
 - Password size 64-bit → 1.8 10¹⁹ combinations



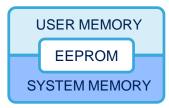
NFC phone / RFID reader

Access from RF



- 3x passwords
- Each memory area can be individually protected by 1 out of 3 available passwords.
- Each area can have a Read / Write access conditions set (area 1 always readable).





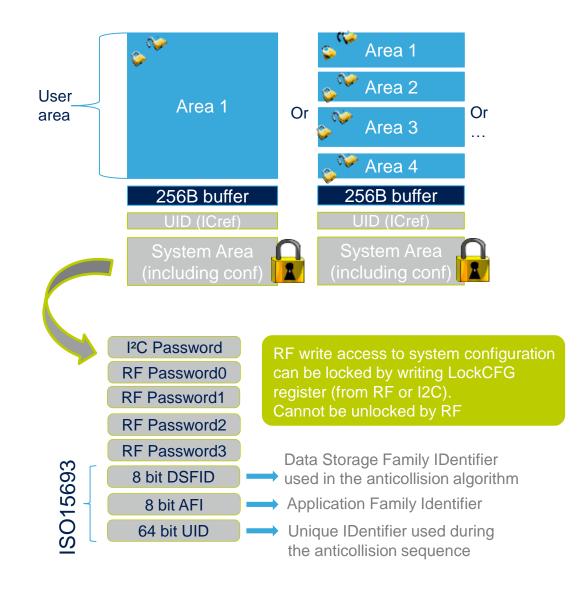
□□ Access from I2C

- 1x password
- Write access can be protected thanks to the I2C password.
- Read access is always allowed (no data protection).
- + 1x configuration password to access configuration bytes in system memory (specific from RF, but same password as memory access password from I2C)



Memory Mapping & Pwd Management

- High Density EEPROM
 - 4-kbit, 16-kbit, 64-kbit
- User EEPROM area configurable in flexible areas (up to 4, granularity 32 bytes)
 - Each area is individually read-/write- protected by password command → 64-bit password
- System EEPROM area
 - Access protected by 64-bit password (Write)
- Specific block used to store a 64-bit UID
 - Unique Identifier accessible form I²C (read only)
 - Its value is written by ST on the production line
 - used during the anticollision sequence (Inventory)
- 256 Bytes Buffer
 - Dedicated Fast Transfer mode
 - Need Vcc ON to be accessible
 - When enabled, write access to user memory (EEPROM) is disabled
- 5 additional 64-bit blocks that stores:
 - 1 I2C password (only accessible from I2C),
 1 RF configuration password (access from RF),
 3 RF area access password codes (access from RF)



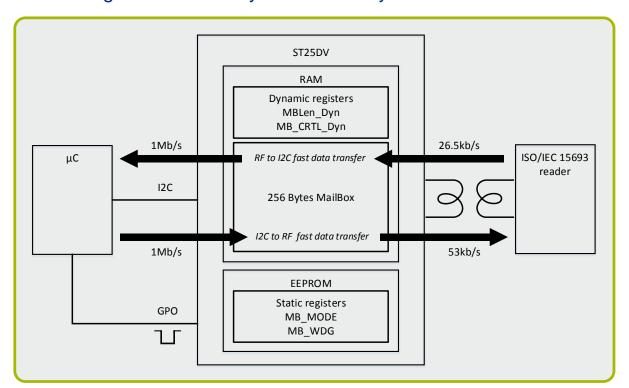




Fast Transfer Mode 14

Fast Transfer Mode Overview

- Fast data transfer between µC and RF reader, ensured through 256 bytes buffer
- RF link up to 53Kb/s (26.5kb/s in write) / I2C link up to 1Mb/s
- Interruption on GPO pin to wake µC on message read and/or message write.
- Status register to inform RF reader or µC of current message status.
- Programmable watchdog to automatically release the system.



Prerequisites

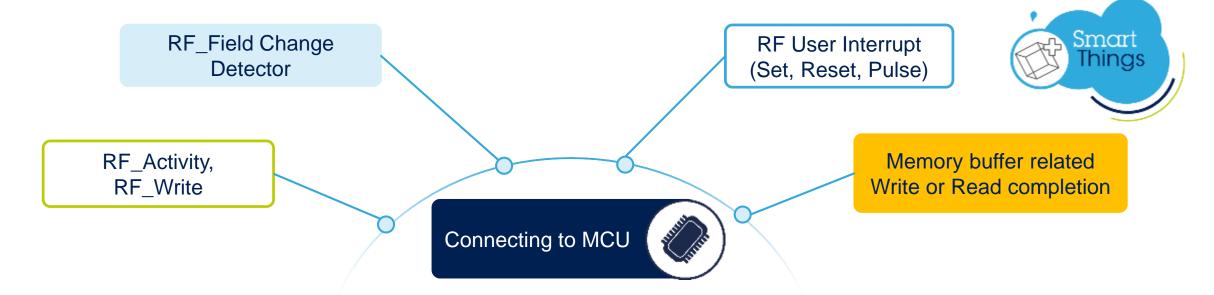
Vcc ON supply must be active to use the 256 Bytes buffer system

Put message is only possible when buffer is empty and enabled





Flexible Interrupts for More Usages



GPO pin → one pin, several options

- User set / reset, pulse
 - Microcontroller wake up
- RF related actions
 - Signaling RF activity / write from RF into EEPROM.
- 256 Bytes memory buffer related
 - End of message write or end of message read in memory buffer
- Field detect
- Output in Open Drain or CMOS

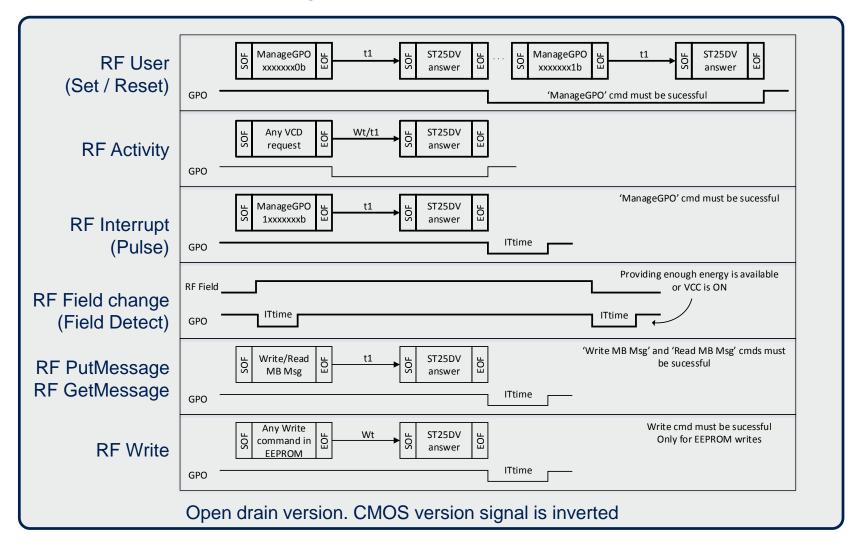
Open-Drain GPO: External pull-up resistor (>4.7 KΩ)





GPO Interruptions 16

GPO Interruption Chronograms



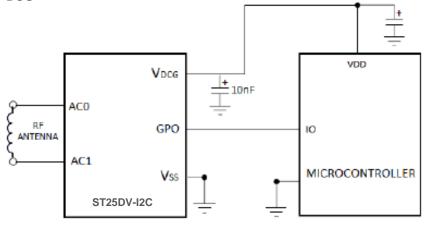


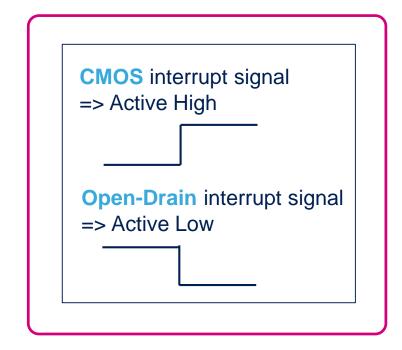


GPO Output Options 17

GPO CMOS

- CMOS interrupt active at High level
- Signal moving from Low to high level (rising edge)
- No need of any external pull-up resistor or RC filtering or transistor.
 - The capacitor (10nF) on V_{DCG} power supply is recommended but not mandatory.
- V_{DCG} and Vss required. V_{DCG} to power CMOS GPO output
 - Current leakage on V_{DCG} pin <100nA (max).





GPO Open Drain



Need external pull up resistor, >4.7 K Ω



12C Interface 18

- I²C (Inter-Integrated Circuit) is typically used for connecting ST25DV-I2C to a micro-controller. It features:
 - Slave I²C serial interface supports 1MHz protocol (I²C fast mode)
 - Single supply voltage: 1.8V to 5.5V
 - Random and sequential read modes
 - Automatic address increment
 - Byte and multiple-bytes write modes (up to 256 bytes, 4 bytes pages internally)
 - No roll over, no cross zone border

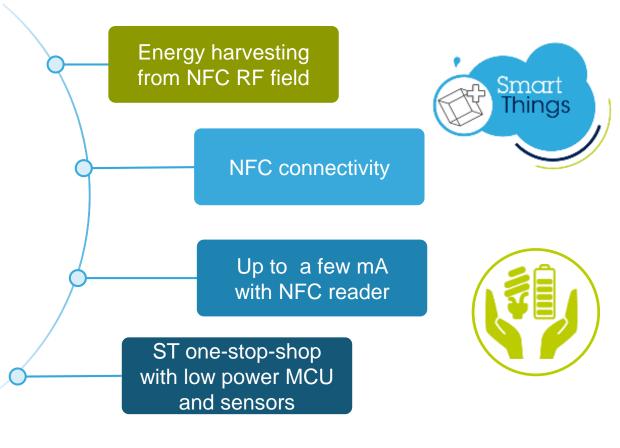
- I²C uses only two lines
 - Serial Clock (SCL)
 - Input signal used to strobe all data in and out of the device
 - Serial Data (SDA), Open drain
 - Bidirectional signal is used to transfer data in or out of the device
 - Pull-up resistor must be connected from SDA to Vcc





Energy Harvesting - Batteryless Design

- The ST25DV-I2C offers Energy Harvesting mode to power external components
 - Part of the non necessary RF power received by the ST25DV-I2C on the AC0-AC1 RF input is delivered through the V_EH pin in order to supply external devices.
- The analog output pin will be able to deliver the analog voltage V_EH whenever the RF field strength is sufficient
 - Delivery of Harvest Energy (up to a few tens μW) on V_EH pin depends on the value of the EH_enable bit located in the dynamic register EH_Dyn
 - Harvest Energy is available at host as soon as surplus energy is available (just limited by RF communication needs)
 - Available Energy depends on antenna, Reader's modulation rate, load and whether RF communication is simultaneously required











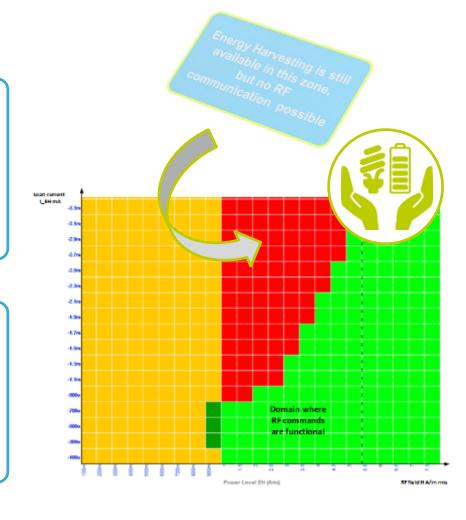
Energy Harvesting Capabilities

- The ST25DV-I2C offers Energy Harvesting suited for your battery less application
 - Guidelines
 - Reader's **AM= 100%** (NFC Forum & ISO15693)

A/m H_EH rms	1	1,5	2	2,5	3	3,5	4	4,5	5
V_EH V	3,25	3,25	3,2	3,15	3,1	2,99	3,05	3,13	3,31
I_EH mA	0,7	0,7	0,9	1,1	1,3	1,9	2,1	2,7	3,1
P_EH mW	2,275	2,275	2,88	3,465	4,03	5,681	6,405	8,451	10,26

• Reader's **AM= 10%** (ISO15693)

A/m H_EH rms	1	1,5	2	2,5	3	3,5	4	4,5	5
V_EH V	3,25	3,25	3,2	3,15	3,1	2,99	3,05	3,13	3,31
I_EH mA	0,7	0,7	0,9	1,1	1,3	1,9	2,5	3,3	4,3
P_EH mW	2,275	2,275	2,88	3,465	4,03	5,681	7,625	10,33	14,23







Energy Harvesting Configuration

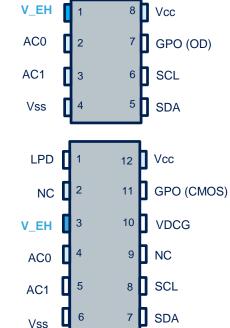
- The ST25DV offers Energy Harvesting mode to power external components through the analog output pin V_EH.
 - The Energy Harvesting mode allows to deliver a part of the non necessary RF power received by the ST25DV on the AC0-AC1 RF inputs in order to supply external devices.
 - To deliver supply voltage on V_EH pin, the RF field must be present (Field_ON) and Energy harvesting must be enabled (EH_EH = 1)

• In case the RF field strength is insufficient or when Energy harvesting mode is disabled, the analog output pin V_EH goes into high-Z state and Energy Harvesting mode is automatically stopped.

- Delivered power is dependent on field power and load
- Power is delivered at V_EH pin as soon as RF_Field is present and sufficient
- 2 control registers (no additional configuration required):
 - EH_MODE allows to force Energy Harvesting at boot or on demand (R/W)
 - EH_CTRL_Dyn allows to switch Energy Harvesting on the fly, whatever the EH_MODE

EH_CTRL_Dyn	Bit description
EH_EN	enable or disable energy harvesting on the fly (R/W)
EH_ON	indicates if energy is delivered on V_EH pin
Field_ON	indicates if RF filed is present (RO)
Vcc_ON	indicates if VCC supply is provided (RO)







RF Interface & Tuning Capacitance

 The internal RF tuning capacitance is 28.5pF which is allowing antenna design from Class 1 to Class 6 form factor.

	ST25DV
Standard	Based on ISO15693 + amendments 3 & 4 NFC Forum type V
Main carrier frequency	13.56MHz
Data sub-carrier frequency	+ 424kHz
Optimal frequency tuning	13.6MHz – 14MHz
Internal capacitor (measured at 0.5V)	28.5pF (*)
Recommended internal capacitor value for antenna design	29pF
Down link speed	Up to 53kbits/s
Single block programming time	< 5ms
Multiple block programming time (max 4 blocks)	< 20ms

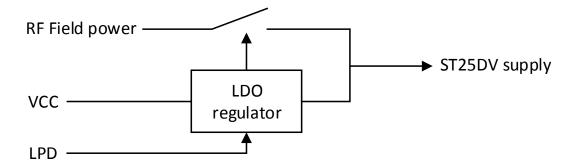






Power Management & Low Power Mode 23

- Power supply
 - 2 possible supply sources: RF field and VCC.
 - ST25DV is supplied by VCC, if present.
 - Access to user memory and system configuration is possible with RF and/or VCC
 - Access memory buffer is possible only if VCC is present.
 - VCC: 1.8V to 5.5V. Internal LDO regulator on VCC.
- Low power mode (with FPN12 and WLCSP10 packages)
 - LPD pin is used to control LDO regulator.
 - When set high, LDO is disabled (power consumption ~ 1µA at VCC=1.8V)
 - → I2C access is disabled (but RF access still possible).

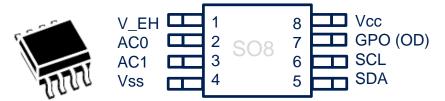






Packages

SO8N Package (4.9x3.9mm)



UFDFPN8 Package (2x3mm)

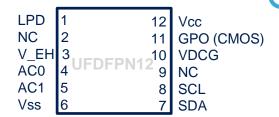




Top view

UFDFPN12 Package (3x3mm)





Top view

3 available pinouts

8 pins: SO8, TSSOP8, UFDFPN8

Open Drain GPO (needs external pull-up)

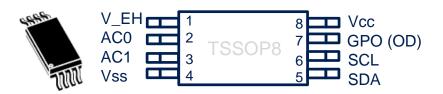
10 pins: WLCSP

CMOS GPO (with VDCG supply pin), LPD input

12 pins : UFDFPN12

CMOS GPO (with VDCG supply pin), LPD input

TSSOP8 Package (3x4.4mm)



 WLCSP Package (1.5x1.7mm), thin, 10 bumps, 400um pitch



Sawn & Bumped wafer



SBN12*

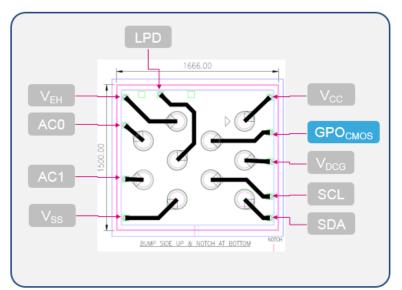
*: sawn and bumped inkless 8" wafer, 120µm thickness



ST25DV04K in WLCSP 25

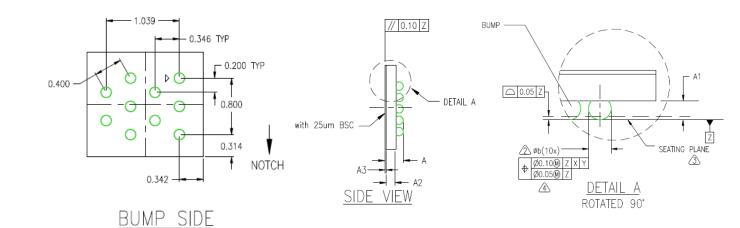
ST25DV04K in WLCSP

- Layout → 10 bumps, 400µm pitch
- Bump metallurgy → SAC 405
- Backside coating → 25μm, black



Dimensions

DIMENSION	MINIMUM	NOMINAL	MAXIMUM
Α	0.265	0.295	0.325
A1	0.080	0.095	0.110
A2	0.150	0.175	0.200
A3	_	0.025	ı
b	0.155	0.185	0.215
NU	IMBER OF	BUMPS: 10	







ST25DV-I2C Support Eco-system 26

Easy-to-use and customer-oriented





ST25DV-I2C Evaluation Boards 27

ST25DV-I2C discovery kit

- ST25DV04K Dynamic NFC tag IC
- 40x24mm 10 turns antenna (ANT Class5)
- STM32F405 MCU
- 2.4" TFT LCD Touch screen
- 12C & SWIP connectors
- Daughter board connector



ST25DV-DISCOVERY

ST25DV-I2C Nucleo shield

- **ST25DV04K** Dynamic NFC tag IC
- Ø54mm 8 turns single layer antenna etched
- Energy harvesting, Low Power mode, GPO
- Compatible with STM32 Nucleo boards
- I2C interface to MCU & Powered through Arduino™ connector





X-NUCLEO-NFC04A1

ST25DV-I2C Antenna kit

- ST25DV04K Dynamic NFC tag IC
- Ready-to-use PCB including:
- 45x75mm (ST25DV_Discovery_ANT_C1)
- 18x24 mm (ST25DV_Discovery_ANT_C6)
- Energy Harvesting output (Vout)
- Mates with ST25Dx_Discovery MBoard





ANT-1-6-ST25DV





Discovery Kit Optional Modules 28

Mother Board WiFi Connector Card usage BLE **HE10** Card Disco Kit No Card for distribution No No Card full Card for demo Yes Yes Yes





http://www.st.com/content/st_com/en/products/wireless-connectivity/bluetooth-bluetooth-low-energy/spbtle-rf.html



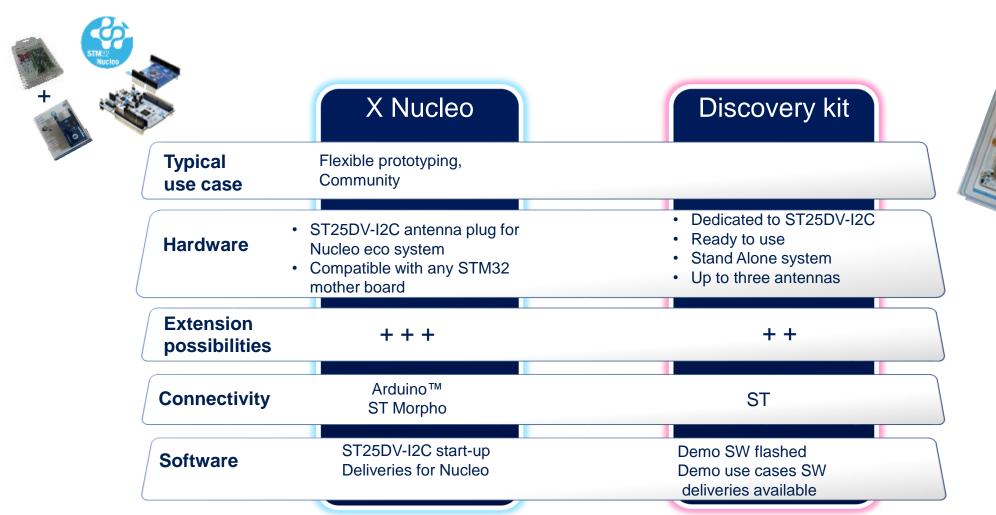




http://www.st.com/content/st com/en/products/wireless-connectivity/wi-fi/spwf01sa.html



Hardware Development Tools Usage







Product Part Numbers 30

ST25DV-I2C	Package	4k-bit	16k-bit	64k-bit
	SO8	ST25DV04K-IER6S3 ST25DV04K-IER8S3	ST25DV16K-IER6S3 ST25DV16K-IER8S3	ST25DV64K-IER6S3 ST25DV64K-IER8S3
Dynamic NFC / RFID tag RF ISO15693 interface + I2C interface	TSSOP8	ST25DV04K-IER6T3 ST25DV04K-IER8T3	ST25DV16K-IER6T3 ST25DV16K-IER8T3	ST25DV64K-IER6T3 ST25DV64K-IER8T3
+ Fast Transfer Mode + GPO + Energy harvesting	FPN8	ST25DV04K-IER6C3 ST25DV04K-IER8C3		
+ Extended temperature	FPN12	ST25DV04K-JFR6D3 ST25DV04K-JFR8D3	ST25DV16K-JFR6D3	ST25DV64K-JFR6D3 ST25DV64K-JFR8D3
	WLCSP10	ST25DV04K-JFR6L3		



Solutions for NFC / RFID Tags and Readers



Thank You!

